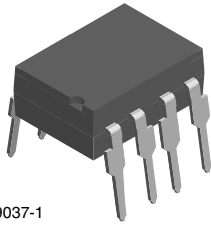
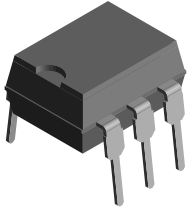
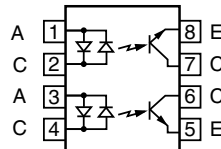
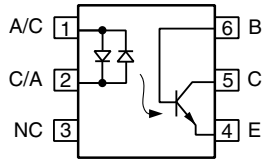




Optocoupler, Phototransistor Output, AC Input, with Base Connection



i179037-1



FEATURES

- AC or polarity insensitive inputs
- Built-in reverse polarity input protection
- Improved CTR symmetry
- Industry standard DIP package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS COMPLIANT

APPLICATIONS

- Ideal for AC signal detection and monitoring

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- CSA 93751
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- CQC

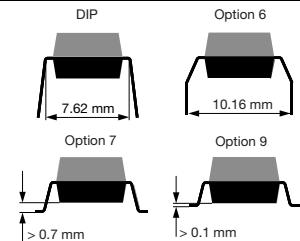
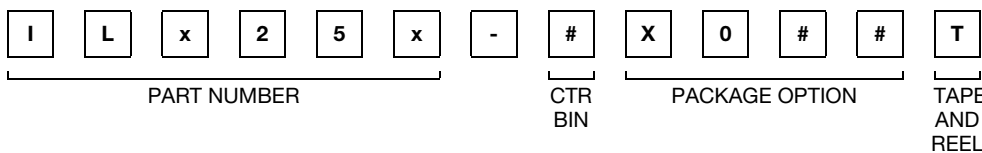
DESCRIPTION

The IL250, IL251, IL252, ILD250, ILD251, ILD252 are bidirectional input optically coupled isolators consisting of two gallium arsenide infrared LEDs coupled to a silicon NPN phototransistor per channel.

The IL250, ILD250 has a minimum CTR of 50 %, the IL251, ILD251 has a minimum CTR of 20 %, and the IL252, ILD252 has a minimum CTR of 100 %.

The IL250, IL251, IL252 are single channel optocouplers. The ILD250, ILD251, ILD252 has two isolated channels in a single DIP package.

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)					
	SINGLE CHANNEL, 6 PIN			DUAL CHANNEL, 8 PIN		
UL, CSA, BSI, CQC	≥ 20	≥ 50	≥ 100	≥ 20	≥ 50	≥ 100
DIP-#	IL251	IL250	IL252	ILD251	ILD250	ILD252
SMD-#, option 7	-	-	IL252-X007T ⁽¹⁾	-	-	-
SMD-#, option 9	IL251-X009T	-	IL252-X009T ⁽¹⁾	-	ILD250-X009T ⁽¹⁾	ILD252-X009T ⁽¹⁾
VDE, UL, CSA, BSI, CQC	≥ 20	≥ 50	≥ 100	≥ 20	≥ 50	≥ 100
DIP-#	-	IL250-X001	IL252-X001	-	-	-
DIP-#, option 6	-	-	IL252-X016	-	-	-
SMD-#, option 7	-	-	IL252-X017T ⁽¹⁾	-	-	ILD252-X017T ⁽¹⁾

Notes

- Additional options may be possible, please contact sales office.
- ⁽¹⁾ Also available in tubes; do not add "T" to end.



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Forward continuous current		I_F	60	mA
Power dissipation		P_{diss}	100	mW
Derate linearly from 25 °C			1.33	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV_{CEO}	30	V
Emitter base breakdown voltage		BV_{EBO}	5	V
Collector base breakdown voltage		BV_{CBO}	70	V
Power dissipation single channel		P_{diss}	200	mW
Power dissipation dual channel		P_{diss}	150	mW
Derate linearly from 25 °C single channel			2.6	mW/°C
Derate linearly from 25 °C dual channel			2	mW/°C
COUPLER				
Isolation test voltage between emitter and detector		V_{ISO}	5300	V_{RMS}
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	10^{12}	Ω
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	10^{11}	Ω
Total dissipation single channel		P_{tot}	250	mW
Total dissipation dual channel		P_{tot}	400	mW
Derate linearly from 25 °C single channel			3.3	mW/°C
Derate linearly from 25 °C dual channel			5.3	mW/°C
Storage temperature		T_{stg}	- 55 to + 150	°C
Operating temperature		T_{amb}	- 55 to + 100	°C
Lead soldering time at 260 °C			10	s

Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = \pm 10\text{ mA}$		V_F		1.2	1.5	V
OUTPUT							
Collector emitter breakdown voltage	$I_C = 1\text{ mA}$		BV_{CEO}	30	50		V
Emitter base breakdown voltage	$I_E = 100\text{ }\mu\text{A}$		BV_{EBO}	7	10		V
Collector base breakdown voltage	$I_C = 10\text{ }\mu\text{A}$		BV_{CBO}	70	90		V
Collector emitter leakage current	$V_{CE} = 10\text{ V}$		I_{CEO}		5	50	nA
COUPLER							
Collector emitter saturation voltage	$I_F = \pm 16\text{ mA}, I_C = 2\text{ mA}$		V_{CEsat}			0.4	V

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$I_F = \pm 10\text{ mA}$, $V_{CE} = 10\text{ V}$	IL250, ILD250	CTR_{DC}	50			%
		IL251, ILD251	CTR_{DC}	20			%
		IL252, ILD252	CTR_{DC}	100			%
Symmetry (CTR at +10 mA)/ (CTR at -10 mA)				0.50	1	2	

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

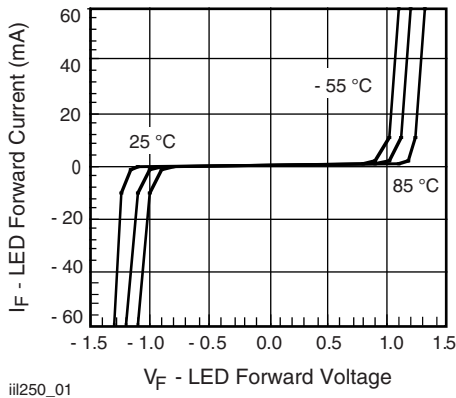


Fig. 1 - LED Forward Current vs. Forward Voltage

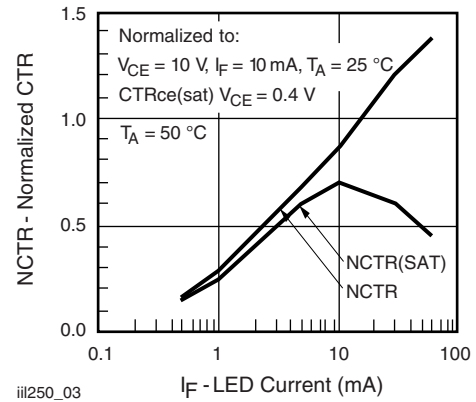


Fig. 3 - Normalized Non-Saturated and Saturated CTR vs. LED Current

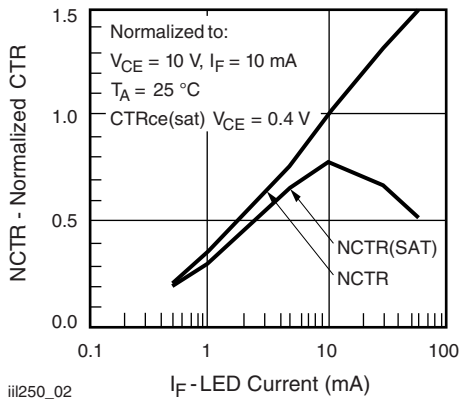


Fig. 2 - Normalized Non-Saturated and Saturated CTR vs. LED Current

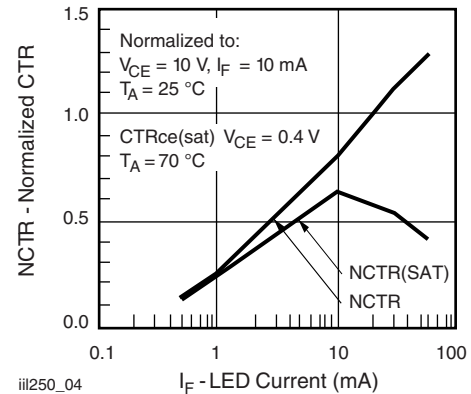


Fig. 4 - Normalized Non-Saturated and Saturated CTR vs. LED Current

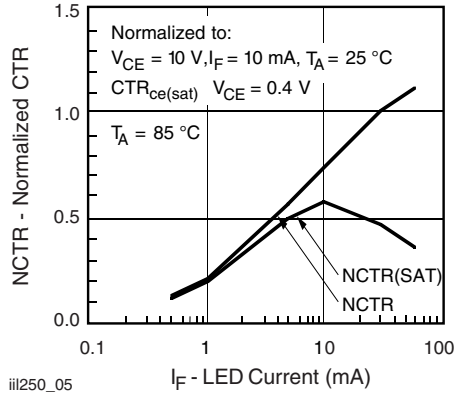


Fig. 5 - Normalized Non-Saturated and Saturated CTR vs. LED Current

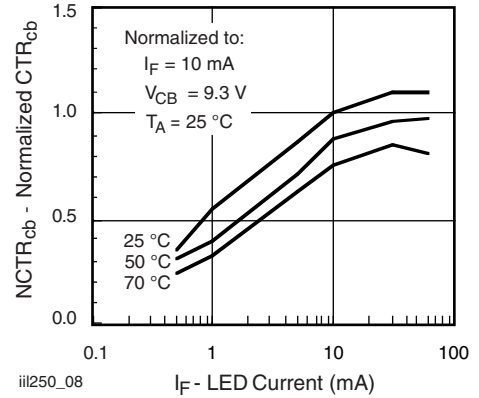


Fig. 8 - Normalized CTR_{CB} vs. LED Current and Temperature

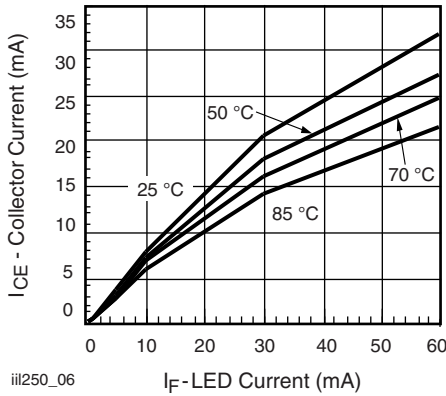


Fig. 6 - Collector Emitter Current vs. Temperature and LED Current

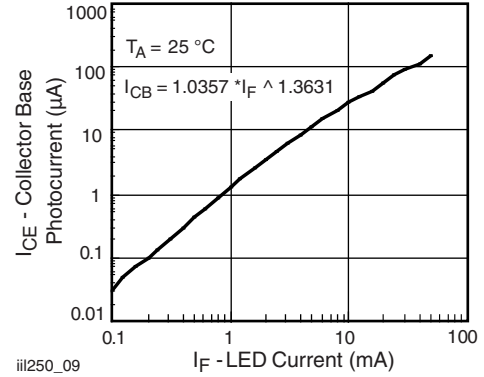


Fig. 9 - Collector Base Photocurrent vs. LED Current

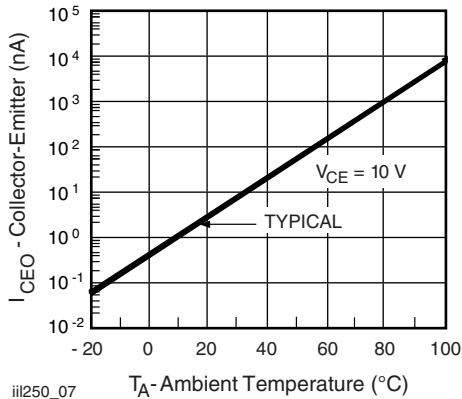


Fig. 7 - Collector Emitter Leakage Current vs. Temperature

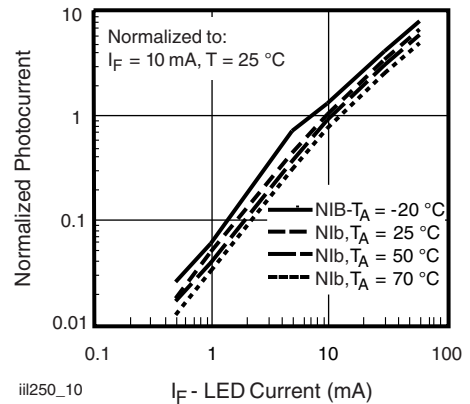


Fig. 10 - Normalized Photocurrent vs. I_F and Temperature

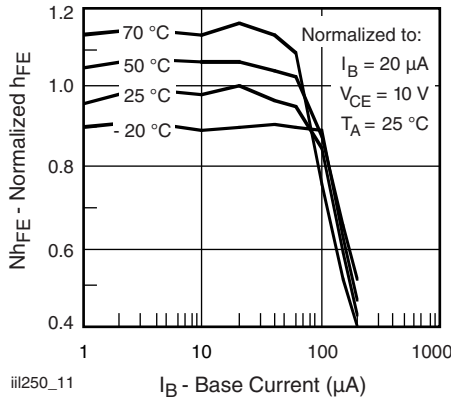


Fig. 11 - Normalized Non Saturated h_{FE} vs. Base Current and Temperature

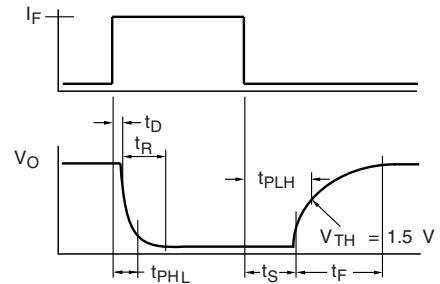


Fig. 14 - Switching Timing

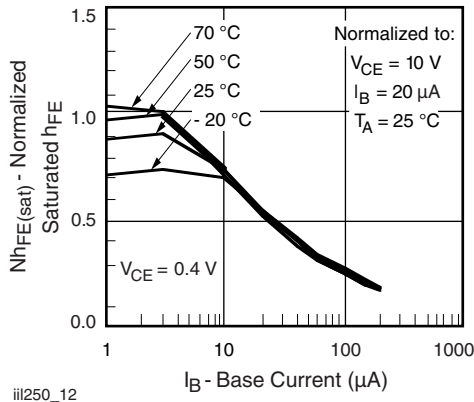


Fig. 12 - Normalized Saturated h_{FE} vs. Base Current and Temperature

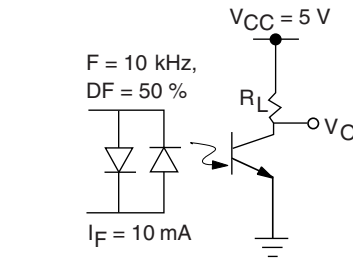


Fig. 15 - Switching Schematic

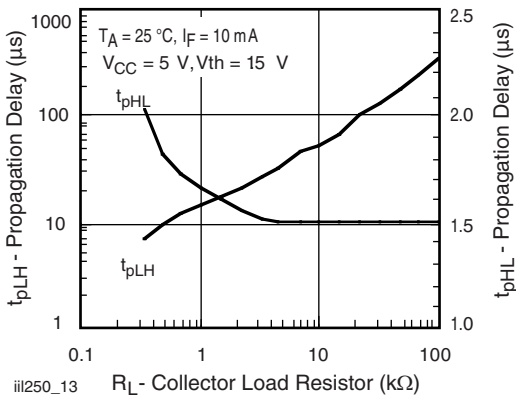
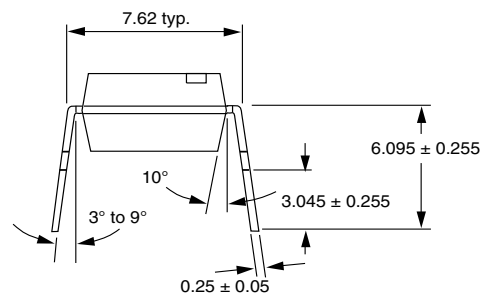
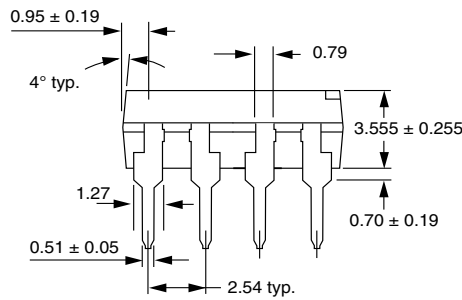
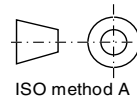
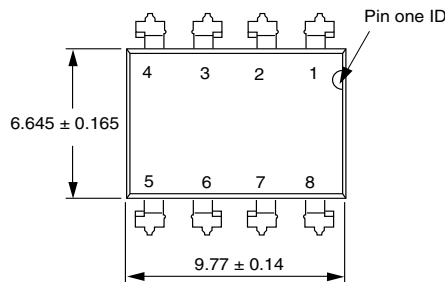
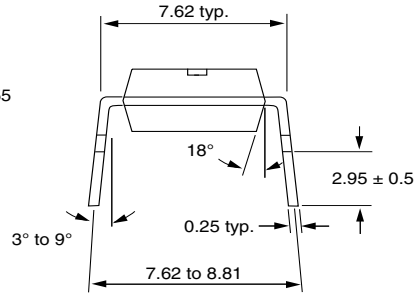
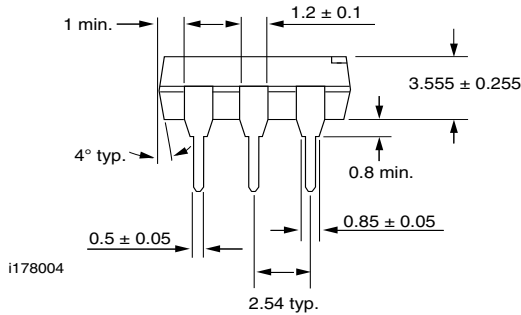
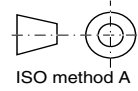
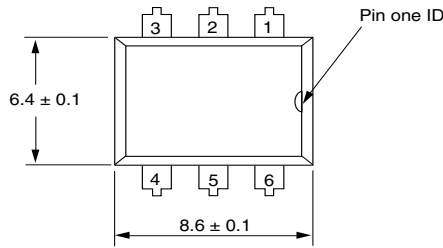


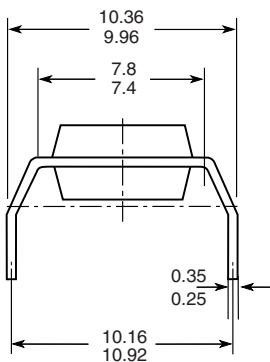
Fig. 13 - Propagation Delay vs. Collector Load Resistor



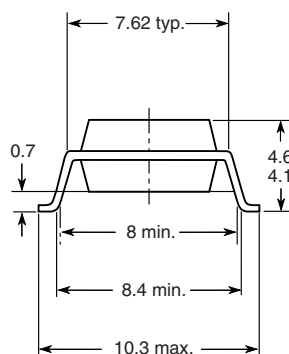
PACKAGE DIMENSIONS in inches (millimeters)



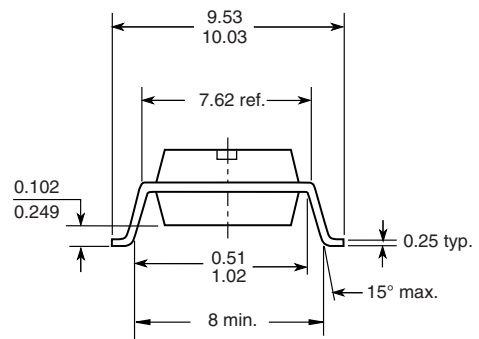
Option 6



Option 7



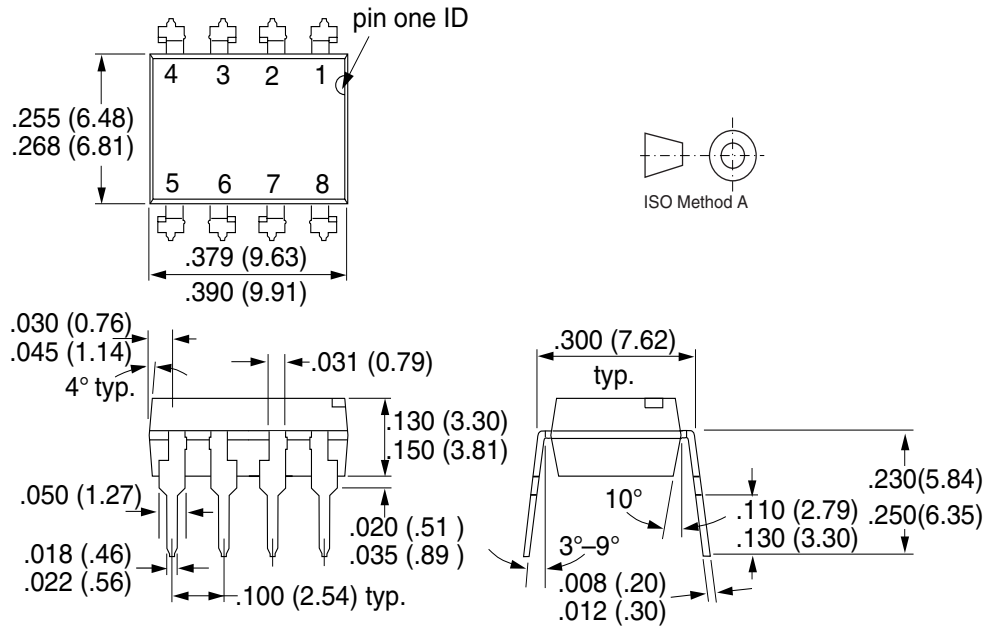
Option 9



18450

DIP-8

Package Dimensions in Inches (mm)



i178006

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2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

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2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
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**We reserve the right to make changes to improve technical design
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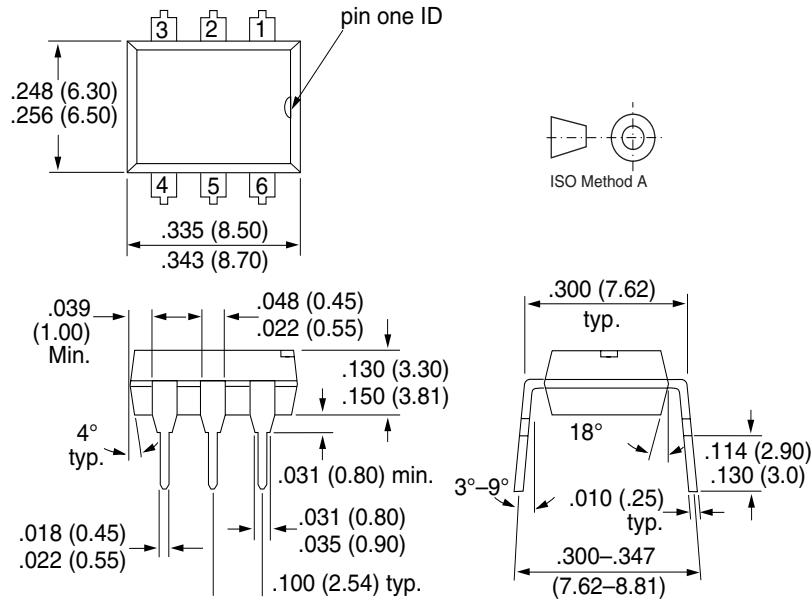
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Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423



DIP-6A

Package Dimensions in Inches (mm)



i178004

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